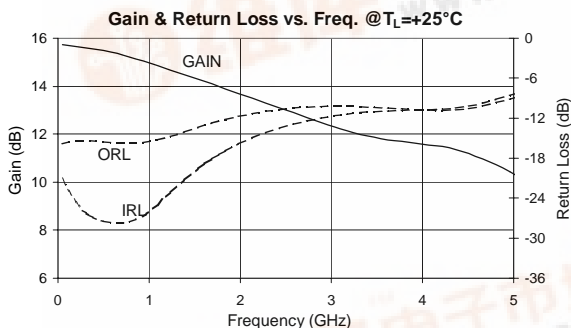


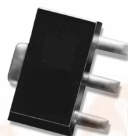
Product Description

Stanford Microdevices' SGA-6389 is a high performance SiGe Heterojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration featuring 1 micron emitters provides high F_T and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. At 850 MHz and 80mA, the SGA-6389 typically provides +35.2 dBm output IP3, 15.7 dB of gain, and +20.2 dBm of 1dB compressed power using a single positive voltage supply. Only 2 DC-blocking capacitors, a bias resistor and an optional RF choke are required for operation.



SGA-6389

DC-4000 MHz, Cascadable SiGe HBT MMIC Amplifier



Product Features

- High Gain : 14.0 dB at 1950 MHz
- Cascadable 50ohm
- Patented InGaP Technology
- Operates From Single Supply
- Low Thermal Resistance Package

Applications

- Cellular, PCS, CDPD
- Wireless Data, SONET
- Satellite

Symbol	Parameter	Units	Frequency	Min.	Typ.	Max.
G	Small Signal Gain	dB	850 MHz	14.1	15.7	17.3
		dB	1950 MHz		14.0	
		dB	2400 MHz		13.3	
P _{1dB}	Output Power at 1dB Compression	dBm	850 MHz		20.2	
		dBm	1950 MHz		18.9	
OIP ₃	Output Third Order Intercept Point (Power out per tone = 0dBm)	dBm	850 MHz		35.2	
		dBm	1950 MHz		32.6	
Bandwidth	Determined by Return Loss (<-10dB)	MHz			4000	
IRL	Input Return Loss	dB	1950 MHz		16.0	
ORL	Output Return Loss	dB	1950 MHz		11.9	
NF	Noise Figure	dB	1950 MHz		4.2	
V _D	Device Voltage	V		4.5	4.9	5.3
R _{Th}	Thermal Resistance				97	



V_S = 8v
 R_{BIAS} = 39 ohms

I_o = 80mA Typ.
 T_L = 25°C

IP3 Tone Spacing = 1 MHz, Pout per tone = 0 dBm
 Z_S = Z_L = 50 Ohms



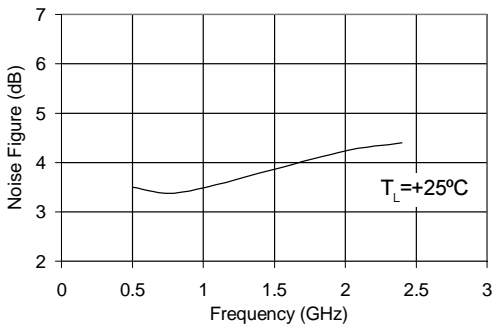
SGA-6389 DC-4000 MHz Cascadable MMIC Amplifier

Typical RF Performance at Key Operating Frequencies

Symbol	Parameter	Unit	Frequency (MHz)					
			100	500	850	1950	2400	3500
G	Small Signal Gain	dB		15.5	15.7	14.0	13.3	.
OIP ₃	Output Third Order Intercept Point	dBm		35.4	35.2	32.6	31.8	
P _{1dB}	Output Power at 1dB Compression	dBm		20.4	20.2	18.9	18.1	
IRL	Input Return Loss	dB	22.3	27.5	27.4	16.0	13.7	11.0
ORL	Output Return Loss	dB	14.7	14.5	14.8	11.9	10.8	10.4
S ₁₂	Reverse Isolation	dB	20.4	20.2	20.3	20.1	19.7	18.2
NF	Noise Figure	dB		3.5	3.4	4.2	4.4	

Test Conditions: V_S = 8v, I_D = 80mA Typ., IP3 Tone Spacing = 1 MHz, Pout per tone = 0 dBm
 R_{BIAS} = 39 ohms, T_L = 25°C, Z_S = Z_L = 50 Ohms

Noise Figure vs. Frequency
V_D = 4.9 V, I_D = 80 mA



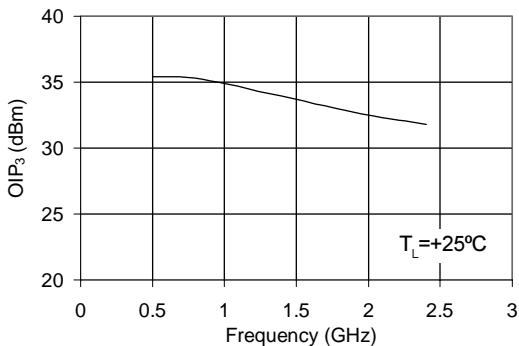
Absolute Maximum Ratings

Parameter	Absolute Limit
Max. Device Current (I _D)	160 mA
Max. Device Voltage (V _D)	7 V
Max. RF Input Power	+16 dBm
Max. Junction Temp. (T _J)	+150°C
Operating Temp. Range (T _L)	-40°C to +85°C
Max. Storage Temp.	+150°C

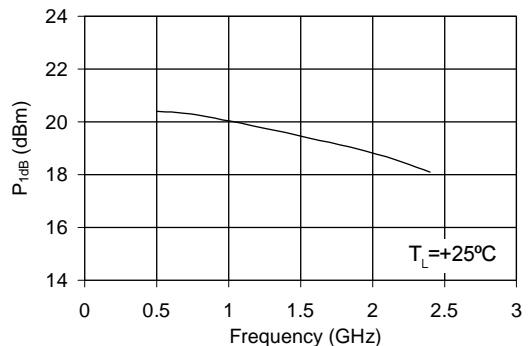
Operation of this device beyond any one of these limits may cause permanent damage.

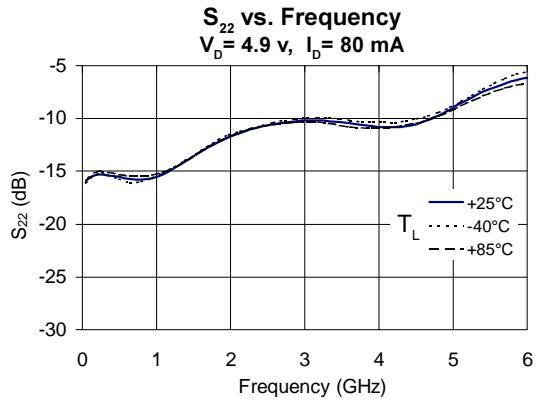
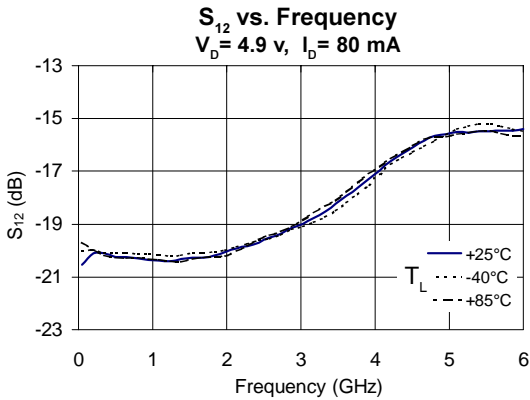
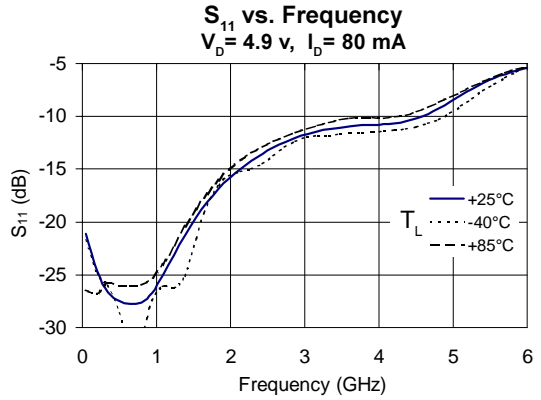
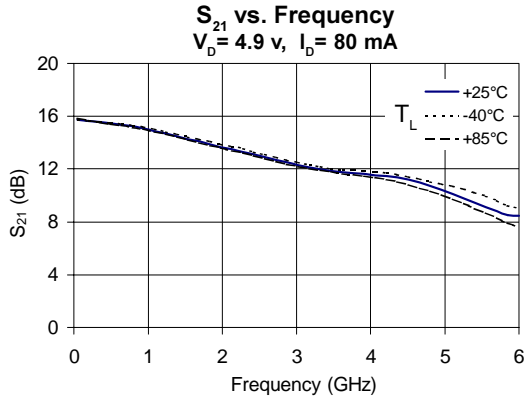
Bias Conditions should also satisfy the following expression: I_DV_D (max) < (T_J - T_L)/R_{th}

OIP₃ vs. Frequency
V_D = 4.9 V, I_D = 80 mA

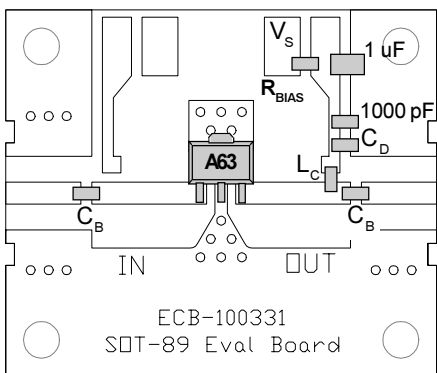
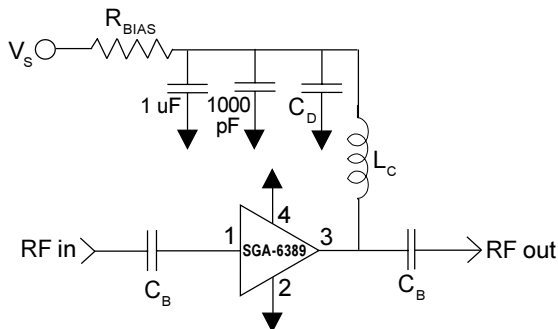


P_{1dB} vs. Frequency
V_D = 4.9 v, I_D = 80 mA



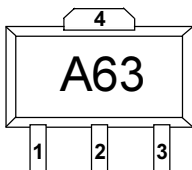


SGA-6389 Basic Application Circuit



Part Identification Marking

The part will be marked with an "A63" designator on the top surface of the package.



For package dimensions, refer to outline drawing at www.stanfordmicro.com

Application Circuit Element Values

Reference Designator	Frequency (Mhz)				
	500	850	1950	2400	3500
C _B	220 pF	100 pF	68 pF	56 pF	39 pF
C _D	100 pF	68 pF	22 pF	22 pF	15 pF
L _C	68 nH	33 nH	22 nH	18 nH	15 nH

Recommended Bias Resistor Values for I_b=80mA

Supply Voltage(Vs)	7.5V	8V	10V	12V
R _{BIAS}	33 Ω	39 Ω	62 Ω	91 Ω

Note: R_{BIAS} provides DC bias stability over temperature.

Mounting Instructions

1. Solder the copper pad on the backside of the device package to the ground plane.
2. Use a large ground pad area with many plated through-holes as shown.
3. We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.
4	GND	Sames as Pin 2

Part Number Ordering Information

Part Number	Reel Size	Devices/Reel
SGA-6389	7"	1000



Caution: ESD sensitive

Appropriate precautions in handling, packaging and testing devices must be observed.